The LTC®4007 is a complete constant-current/constant-voltage charger controller for 3- or 4-cell lithium-ion batteries. The PWM controller uses a synchronous, quasi-constant frequency, constant off-time architecture that will not generate audible noise even when using ceramic capacitors. Charging current is programmable to ±4% accuracy using a programming resistor. Charging current can also be monitored as a voltage across the programming resistor.

The output float voltage is pin programmed for cell count (3 cells or 4 cells) and chemistry (4.2V/4.1V). A timer, programmed by an external resistor, sets the charge termination time. Charging is automatically restarted when cell voltage falls below 3.9V/cell.

LTC4007 includes a thermistor input, which suspends charging if an unsafe temperature condition is detected. If the cell voltage is less than 2.5V, a low-battery indicator asserts and can be used to program a trickle charge current to safely charge depleted batteries. The FAULT pin is also asserted and charging terminates if the low-battery condition persists for more than 1/4 of the total charge time.

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LTC4007

**ABSOLUTE MAXIMUM RATINGS**

(Note 1)
Voltage from DCIN, CLP, CLN to GND ........... +32V/–0.3V
PGND with Respect to GND .......................... ±0.3V
CSP, BAT to GND .................................. +28V/–0.3V
CHEM, 3C4C, RT to GND .......................... +7V/–0.3V
NTC .................................................. +10V/–0.3V
ACP, SHDN, CHG, FLAG,
FAULT, LOBAT, ICL .................................. +32V/–0.3V
CLP to CLN .......................................... ±0.5V

Operating Ambient Temperature Range
(Note 4) ........................................... –40°C to 85°C
Operating Junction Temperature .......... –40°C to 125°C
Storage Temperature Range ............... –65°C to 150°C
Lead Temperature (Soldering, 10 sec) .......... 300°C

**ORDER INFORMATION**

http://www.linear.com/product/LTC4007#orderinfo

**LEAD FREE FINISH**

<table>
<thead>
<tr>
<th>LTC4007EGN#PBF</th>
<th>LTC4007EGN#TRPBF</th>
<th>LTC4007EGN</th>
<th>24-Lead Plastic SSOP</th>
<th>–40°C to 85°C</th>
</tr>
</thead>
</table>

Consult ADI Marketing for parts specified with wider operating temperature ranges.
For more information on lead free part marking, go to: http://www.linear.com/leadfree/
For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/. Some packages are available in 500 unit reels through designated sales channels with #TRMPBF suffix.

**ELECTRICAL CHARACTERISTICS**

The ● denotes the specifications which apply over the full operating temperature range (Note 4), otherwise specifications are at TA = 25°C. VDCIN = 20V, VBAT = 12V unless otherwise noted.

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
</tr>
</thead>
<tbody>
<tr>
<td>DCIN Operating Range</td>
<td>6</td>
<td>28</td>
<td>V</td>
<td></td>
<td></td>
</tr>
<tr>
<td>VCC Operating Current</td>
<td>3</td>
<td>5</td>
<td>mA</td>
<td></td>
<td></td>
</tr>
<tr>
<td>VCC Charge Voltage Accuracy</td>
<td>0.8</td>
<td>0.8</td>
<td>%</td>
<td></td>
<td></td>
</tr>
<tr>
<td>VCC Charge Current Accuracy (Note 3)</td>
<td>4</td>
<td>4</td>
<td>%</td>
<td></td>
<td></td>
</tr>
<tr>
<td>VCC Termination Timer Accuracy</td>
<td>15</td>
<td>15</td>
<td>%</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Battery Leakage Current</td>
<td>–10</td>
<td>15</td>
<td>35</td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td>UVLO Undervoltage Lockout Threshold</td>
<td>4.2</td>
<td>4.7</td>
<td>5.5</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>Shutdown Threshold at SHDN</td>
<td>1</td>
<td>1.6</td>
<td>2.5</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>SHDN Pin Current</td>
<td>–10</td>
<td></td>
<td>µA</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Operating Current in Shutdown</td>
<td>2</td>
<td>3</td>
<td>mA</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>
### Electrical Characteristics

The ● denotes the specifications which apply over the full operating temperature range (Note 4), otherwise specifications are at $T_A = 25^\circ C$, $V_{DCIN} = 20V$, $V_BAT = 12V$ unless otherwise noted.

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>Current Sense Amplifier, CA1</td>
<td>Input Bias Current Into BAT Pin</td>
<td>11.67</td>
<td>µA</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>CMSL</td>
<td>CA1/$I_1$ Input Common Mode Low</td>
<td>●</td>
<td>0</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td></td>
<td>CMSG</td>
<td>CA1/$I_1$ Input Common Mode High</td>
<td>●</td>
<td>$V_{CLN} – 0.2$</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>Current Comparators $I_{CMP}$ and $I_{REV}$</td>
<td>$I_{MAX}$</td>
<td>Maximum Current Sense Threshold ($V_{CSP} – V_{BAT}$)</td>
<td>$V_{ITH} = 2.5V$</td>
<td>●</td>
<td>140</td>
<td>165</td>
</tr>
<tr>
<td></td>
<td>$I_{REV}$</td>
<td>Reverse Current Threshold ($V_{CSP} – V_{BAT}$)</td>
<td></td>
<td></td>
<td></td>
<td>$-30$</td>
</tr>
<tr>
<td>Current Sense Amplifier, CA2</td>
<td>Transconductance</td>
<td></td>
<td></td>
<td></td>
<td>1</td>
<td>mmho</td>
</tr>
<tr>
<td></td>
<td>Source Current</td>
<td>Measured at $I_{TH}$, $V_{ITH} = 1.4V$</td>
<td></td>
<td></td>
<td>$-40$</td>
<td>µA</td>
</tr>
<tr>
<td></td>
<td>Sink Current</td>
<td>Measured at $I_{TH}$, $V_{ITH} = 1.4V$</td>
<td></td>
<td></td>
<td>$40$</td>
<td>µA</td>
</tr>
<tr>
<td>Current Limit Amplifier</td>
<td>Transconductance</td>
<td></td>
<td></td>
<td></td>
<td>1.4</td>
<td>mmho</td>
</tr>
<tr>
<td></td>
<td>$V_{CLP}$</td>
<td>Current Limit Threshold</td>
<td></td>
<td>●</td>
<td>93</td>
<td>100</td>
</tr>
<tr>
<td></td>
<td>$I_{CLP}$</td>
<td>CLP Input Bias Current</td>
<td></td>
<td></td>
<td>100</td>
<td>nA</td>
</tr>
<tr>
<td>Voltage Error Amplifier, EA</td>
<td>Transconductance</td>
<td></td>
<td></td>
<td></td>
<td>1</td>
<td>mmho</td>
</tr>
<tr>
<td></td>
<td>Sink Current</td>
<td>Measured at $I_{TH}$, $V_{ITH} = 1.4V$</td>
<td></td>
<td></td>
<td>$36$</td>
<td>µA</td>
</tr>
<tr>
<td></td>
<td>$OVSD$</td>
<td>Overvoltage Shutdown Threshold as a Percent of Programmed Charger Voltage</td>
<td></td>
<td>●</td>
<td>102</td>
<td>107</td>
</tr>
<tr>
<td>Input P-Channel FET Driver (INFET)</td>
<td>$DCIN$ Detection Threshold ($V_{DCIN} – V_{CLN}$)</td>
<td>DCIN Voltage Ramping Up from $V_{CLN} – 0.1V$</td>
<td></td>
<td></td>
<td>●</td>
<td>0</td>
</tr>
<tr>
<td></td>
<td>Forward Regulation Voltage ($V_{DCIN} – V_{CLN}$)</td>
<td></td>
<td></td>
<td></td>
<td>●</td>
<td>25</td>
</tr>
<tr>
<td></td>
<td>Reverse Voltage Turn-Off Voltage ($V_{DCIN} – V_{CLN}$)</td>
<td>DCIN Voltage Ramping Down</td>
<td></td>
<td></td>
<td>●</td>
<td>$-60$</td>
</tr>
<tr>
<td></td>
<td>INFET “On” Clamping Voltage ($V_{DCIN} – V_{INFET}$)</td>
<td>$I_{INFET} = 1µA$</td>
<td></td>
<td></td>
<td>●</td>
<td>5</td>
</tr>
<tr>
<td></td>
<td>INFET “Off” Clamping Voltage ($V_{DCIN} – V_{INFET}$)</td>
<td>$I_{INFET} = -25µA$</td>
<td></td>
<td></td>
<td></td>
<td>0.25</td>
</tr>
<tr>
<td>Thermistor</td>
<td>NTCVR</td>
<td>Reference Voltage During Sample Time</td>
<td></td>
<td></td>
<td>4.5</td>
<td>V</td>
</tr>
<tr>
<td></td>
<td>High Threshold</td>
<td>$V_{NTC}$ Rising</td>
<td></td>
<td>●</td>
<td>NTCVR</td>
<td>NTCVR</td>
</tr>
<tr>
<td></td>
<td>Low Threshold</td>
<td>$V_{NTC}$ Falling</td>
<td></td>
<td>●</td>
<td>NTCVR</td>
<td>NTCVR</td>
</tr>
<tr>
<td></td>
<td>Thermistor Disable Current</td>
<td>$V_{NTC} ≤ 10V$</td>
<td></td>
<td></td>
<td>10</td>
<td>µA</td>
</tr>
<tr>
<td>Indicator Outputs (ACP, CHG, FLAG, LOBAT, ICL, FAULT)</td>
<td>C10TOL</td>
<td>FLAG (C/10) Accuracy</td>
<td>Voltage Falling at PROG</td>
<td></td>
<td>●</td>
<td>0.375</td>
</tr>
<tr>
<td></td>
<td>LBTL</td>
<td>LOBAT Threshold Accuracy</td>
<td></td>
<td></td>
<td>3C4C = 0V, CHEM = 0V</td>
<td>7.10</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>3C4C = 0V, CHEM = Open</td>
<td>7.27</td>
<td>7.50</td>
<td>7.71</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>3C4C = Open, CHEM = 0V</td>
<td>9.46</td>
<td>9.76</td>
<td>10.10</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>3C4C = Open, CHEM = Open</td>
<td>9.70</td>
<td>10</td>
<td>10.28</td>
</tr>
<tr>
<td></td>
<td>RESTART Threshold Accuracy</td>
<td></td>
<td></td>
<td></td>
<td>3C4C = 0V, CHEM = 0V</td>
<td>11.13</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>3C4C = 0V, CHEM = Open</td>
<td>11.40</td>
<td>11.70</td>
<td>11.94</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>3C4C = Open, CHEM = 0V</td>
<td>14.84</td>
<td>15.23</td>
<td>15.54</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>3C4C = Open, CHEM = Open</td>
<td>15.20</td>
<td>15.60</td>
<td>15.92</td>
</tr>
<tr>
<td></td>
<td>ICL Threshold Accuracy</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>83</td>
</tr>
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</table>
## ELECTRICAL CHARACTERISTICS

The • denotes the specifications which apply over the full operating temperature range (Note 4), otherwise specifications are at TA = 25°C. VDCIN = 20V, VBAT = 12V unless otherwise noted.

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>V_{OL}</td>
<td>Low Logic Level of ACP, CHG, FLAG, LOBAT, ICL, FAULT</td>
<td>I_{OL} = 100µA •</td>
<td>0.5</td>
<td>V</td>
<td></td>
<td></td>
</tr>
<tr>
<td>V_{OH}</td>
<td>High Logic Level of CHG, LOBAT, ICL</td>
<td>I_{OH} = 1µA •</td>
<td>2.7</td>
<td>V</td>
<td></td>
<td></td>
</tr>
<tr>
<td>I_{OFF}</td>
<td>Off State Leakage Current of ACP, FLAG, FAULT</td>
<td>V_{OSH} = 3V</td>
<td>-1</td>
<td>1</td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td>I_{PO}</td>
<td>Pull-Up Current on CHG, LOBAT, ICL</td>
<td>V = 0V</td>
<td>-10</td>
<td>µA</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>Charge Termination Defeat Threshold at CHG</td>
<td></td>
<td>1</td>
<td>V</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

### Programming Inputs (CHEM and 3C4C)

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>V_{IH}</td>
<td>High Logic Level</td>
<td>•</td>
<td>3.3</td>
<td>V</td>
<td></td>
<td></td>
</tr>
<tr>
<td>V_{IL}</td>
<td>Low Logic Level</td>
<td>•</td>
<td>1</td>
<td>V</td>
<td></td>
<td></td>
</tr>
<tr>
<td>I_{PI}</td>
<td>Pull-Up Current</td>
<td>V = 0V</td>
<td>-14</td>
<td>µA</td>
<td></td>
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</table>

### Oscillator

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>f_{OSC}</td>
<td>Regulator Switching Frequency</td>
<td></td>
<td>255</td>
<td>300</td>
<td>345</td>
<td>kHz</td>
</tr>
<tr>
<td>f_{MIN}</td>
<td>Regulator Switching Frequency in Drop Out</td>
<td>Duty Cycle ≥ 98%</td>
<td>20</td>
<td>25</td>
<td>kHz</td>
<td></td>
</tr>
<tr>
<td>DC_{MAX}</td>
<td>Regulator Maximum Duty Cycle</td>
<td>V_{CSP} = V_{BAT}</td>
<td>98</td>
<td>99</td>
<td>%</td>
<td></td>
</tr>
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</table>

### Gate Drivers (TGATE, BGATE)

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>V_{TGATE High}</td>
<td>(V_{CLN} – V_{TGATE})</td>
<td>I_{TGATE} = -1mA</td>
<td>50</td>
<td>mV</td>
<td></td>
<td></td>
</tr>
<tr>
<td>V_{BGATE High}</td>
<td></td>
<td>C_{LOAD} = 3000pF</td>
<td>4.5</td>
<td>5.6</td>
<td>10</td>
<td>V</td>
</tr>
<tr>
<td>V_{TGATE Low}</td>
<td>(V_{CLN} – V_{TGATE})</td>
<td>C_{LOAD} = 3000pF</td>
<td>4.5</td>
<td>5.6</td>
<td>10</td>
<td>V</td>
</tr>
<tr>
<td>V_{BGATE Low}</td>
<td></td>
<td>I_{BGATE} = 1mA</td>
<td>50</td>
<td>mV</td>
<td></td>
<td></td>
</tr>
<tr>
<td>TGTR</td>
<td>TGATE Transition Time</td>
<td>C_{LOAD} = 3000pF, 10% to 90%</td>
<td>50</td>
<td>110</td>
<td>ns</td>
<td></td>
</tr>
<tr>
<td>TGTF</td>
<td>TGATE Rise Time</td>
<td>C_{LOAD} = 3000pF, 10% to 90%</td>
<td>50</td>
<td>100</td>
<td>ns</td>
<td></td>
</tr>
<tr>
<td>BGTR</td>
<td>BGATE Transition Time</td>
<td>C_{LOAD} = 3000pF, 10% to 90%</td>
<td>40</td>
<td>90</td>
<td>ns</td>
<td></td>
</tr>
<tr>
<td>BGTG</td>
<td>BGATE Rise Time</td>
<td>C_{LOAD} = 3000pF, 10% to 90%</td>
<td>40</td>
<td>80</td>
<td>ns</td>
<td></td>
</tr>
<tr>
<td>V_{TGATE at Shutdown}</td>
<td>(V_{CLN} – V_{TGATE})</td>
<td>I_{TGATE} = -1µA, DCIN = 0V, CLN = 12V</td>
<td></td>
<td>100</td>
<td>mV</td>
<td></td>
</tr>
<tr>
<td>V_{BGATE at Shutdown}</td>
<td></td>
<td>I_{BGATE} = 1µA, DCIN = 0V, CLN = 12V</td>
<td></td>
<td>100</td>
<td>mV</td>
<td></td>
</tr>
</tbody>
</table>

### Notes

**Note 1:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

**Note 2:** See “Test Circuit”.

**Note 3:** Does not include tolerances of current sense resistor or current programming resistor.

**Note 4:** The LTC4007E is guaranteed to meet performance specifications from 0°C to 70°C. Specifications over the –40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.
TYPICAL PERFORMANCE CHARACTERISTICS

INFET Response Time to Reverse Current

PWM Frequency vs Duty Cycle

Line Regulation

VOUT vs IOUT

Disconnect/Reconnect Battery (Load Dump)

1A Load Step (Battery Present)

1A Load Step (Battery Not Present)

Battery Leakage Current vs Battery Voltage

For more information www.analog.com
TYPICAL PERFORMANCE CHARACTERISTICS

Efficiency at 19VDC $V_{IN}$

![Graph showing efficiency at 19VDC $V_{IN}$]

Efficiency at 12.6V with 15VDC $V_{IN}$

![Graph showing efficiency at 12.6V with 15VDC $V_{IN}$]

PIN FUNCTIONS

**DCIN (Pin 1):** External DC Power Source Input. Bypass this pin with at least 0.01µF. See "Applications Information".

**CHG (Pin 2):** Charge Status Output. When the battery is being charged, the CHG pin is pulled low by an internal N-channel MOSFET. Internal 10µA pull-up to 3.5V. If $V_{LOGIC}$ is greater than 3.3V, add an external pull-up. The timer charge termination can be defeated by forcing this pin below 1V (or connecting it to GND).

**ACP (Pin 3):** Open-Drain output to indicate if the AC adapter voltage is adequate for charging. This pin is pulled low by an internal N-channel MOSFET if DCIN is below BAT. A pull-up resistor is required. The pin is capable of sinking at least 100µA.

**RT (Pin 4):** Timer Resistor. The timer period is set by placing a resistor, $R_{RT}$, to GND. This resistor is always required.

The timer period is $t_{TIMER} = (1\text{hour} \cdot R_{RT}/154$K$).

If this resistor is not present, the charger will not start.

**LOBAT (Pin 8):** Low-Battery Indicator. Active low digital output. Internal 10µA pull-up to 3.5V. If the battery voltage is below 2.5V/cell (or 2.44V/cell for 4.1V chemistry batteries) LOBAT will be low. The pin is capable of sinking at least 100µA. If $V_{LOGIC}$ is greater than 3.3V, add an external pull-up.

**NTC (Pin 9):** A thermistor network is connected from NTC to GND. This pin determines if the battery temperature is safe for charging. The charger and timer are suspended and the FAULT pin is driven low if the thermistor indicates a temperature that is unsafe for charging. The thermistor function may be disabled with a 300k to 500k resistor from DCIN to NTC.
PIN FUNCTIONS

ITH (Pin 10): Control Signal of the Inner Loop of the Current Mode PWM. Higher ITH voltage corresponds to higher charging current in normal operation. A 6k resistor, in series with a capacitor of at least 0.1µF to GND provides loop compensation. Typical full-scale output current is 40µA. Nominal voltage range for this pin is 0V to 3V.

PROG (Pin 11): Current Programming/Monitoring Input/Output. An external resistor to GND programs the peak charging current in conjunction with the current sensing resistor. The voltage at this pin provides a linear indication of charging current. Peak current is equivalent to 1.19V. Zero current is approximately 0.3V. A capacitor from PROG to ground is required to filter higher frequency components. The maximum resistance to ground is 100k. Values higher than 100k can cause the charger to shut down.

NC (Pin 12): No Connect.

I_CL (Pin 13): Input Current Limit Indicator. Active low digital output. Internal 10µA pull-up to 3.5V. Pulled low if the charger current is being reduced by the input current limiting function. The pin is capable of sinking at least 100µA. If V_LOGIC is greater than 3.3V, add an external pull-up.

CSP (Pin 14): Current Amplifier CA1 Input. The CSP and BAT pins measure the voltage across the sense resistor, R_SENSE, to provide the instantaneous current signals required for both peak and average current mode operation.

BAT (Pin 15): Battery Sense Input and the Negative Reference for the Current Sense Resistor. A precision internal resistor divider sets the final float potential on this pin. The resistor divider is disconnected during shutdown.

CHEM (Pin 16): Select 4.1V or 4.2V cell chemistry by connecting the pin to GND or open, respectively. Internal 14µA pull-up to 5.3V. Can also be driven with open-collector/drain logic levels.

FLAG (Pin 17): Active low open-drain output that indicates when charging current has declined to 10% of maximum programmed current. A pull-up resistor is required if this function is used. The pin is capable of sinking at least 100µA.

CLP (Pin 18): Positive input to the supply current limiting amplifier, CL1. The threshold is set at 100mV above the voltage at the CLN pin. When used to limit supply current, a filter is needed to filter out the switching noise. If no current limit function is desired, connect this pin to CLN.

CLN (Pin 19): Negative Reference for the Input Current Limit Amplifier, CL1. This pin also serves as the power supply for the IC. A 10µF to 22µF bypass capacitor should be connected as close as possible to this pin.

TGATE (Pin 20): Drives the top external P-channel MOSFET of the battery charger buck converter.

PGND (Pin 21): High Current Ground Return for the BGATE Driver.

BGATE (Pin 22): Drives the bottom external N-channel MOSFET of the battery charger buck converter.

INFET (Pin 23): Drives the Gate of the External Input PFET.

SHDN (Pin 24): Charger is shut down and timer is reset when this pin is HIGH. Internal 10µA pull-up to 3.5V. This pin can also be used to reset the charger by applying a positive pulse that is a minimum of 0.1µs long.

For more information www.analog.com
OPERATION

Overview

The LTC4007 is a synchronous current mode PWM step-down (buck) switcher battery charger controller. The charge current is programmed by the combination of a program resistor (R\text{PROG}) from the PROG pin to ground and a sense resistor (R\text{SENSE}) between the CSP and BAT pins. The final float voltage is programmed to one of four values (12.3V, 12.6V, 16.4V, 16.8V) with ±1% maximum accuracy using pins 3C4C and CHEM. Charging begins when the potential at the DCIN pin rises above the voltage at BAT (and the UVLO voltage) and the SHDN pin is low; the \text{CHG} pin is set low. At the beginning of the charge cycle, if the cell voltage is below 2.5V (2.44V if CHEM is low), the \text{LOBAT} pin will be low. The \text{LOBAT} indicator can be used to reduce the charging current to a low value, typically 10% of full scale. If the cell voltage stays below 2.5V for 25% of the total charge time, the charge sequence will be terminated immediately and the \text{FAULT} pin will be set low.

An external thermistor network is sampled at regular intervals. If the thermistor value exceeds design limits, charging is suspended and the \text{FAULT} pin is set low. If the thermistor value returns to an acceptable value, charging resumes and the \text{FAULT} pin is set high. An external resistor on the R\text{T} pin sets the charge termination time. Charge termination can be defeated by forcing the \text{CHG} pin to a low voltage.

As the battery approaches the final float voltage, the charge current will begin to decrease. When the current drops to 10% of the full-scale charge current, an internal C/10 comparator will indicate this condition by latching the \text{FLAG} pin low. The charge timer is also reset to 1/4 of the total charge time when \text{FLAG} goes low. If this condition is caused by an input current limit condition, described below, then the \text{FLAG} indicator will be inhibited. When a time-out occurs, charging is terminated immediately and the \text{CHG} pin is forced to a high impedance state. The charger will automatically restart if the cell voltage is below 3.9V (or 3.81V if CHEM is low). To restart the charge cycle manually, simply remove the input voltage and reapply it, or set the SHDN pin high momentarily. When the input voltage is not present, the charger goes into a sleep mode, dropping battery current drain to 15µA. This greatly reduces the current drain on the battery and increases the standby time. The charger is inhibited any time the SHDN pin is high.

Input FET

The input FET circuit performs two functions. It enables the charger if the input voltage is higher than the CLN pin and provides the logic indicator of AC present on the ACP pin. It controls the gate of the input FET to keep a low forward voltage drop when charging and also prevents reverse current flow through the input FET.

If the input voltage is less than V\text{CLN}, it must go at least 170mV higher than V\text{CLN} to activate the charger. When this occurs the ACP pin is released and pulled up with an external load to indicate that the adapter is present. The gate of the input FET is driven to a voltage sufficient
to keep a low forward voltage drop from drain to source. If the voltage between DCIN and CLN drops to less than 25mV, the input FET is turned off slowly. If the voltage between DCIN and CLN is ever less than –25mV, then the input FET is turned off in less than 10µs to prevent significant reverse current from flowing in the input FET. In this condition, the ACP pin is driven low and the charger is disabled.

**Battery Charger Controller**

The LTC4007 charger controller uses a constant off-time, current mode step-down architecture. During normal operation, the top MOSFET is turned on each cycle when the oscillator sets the SR latch and turned off when the main current comparator I\text{CMP} resets the SR latch. While the top MOSFET is off, the bottom MOSFET is turned on until either the inductor current trips the current comparator I_{REV} or the beginning of the next cycle. The oscillator uses the equation:

\[ t_{OFF} = \frac{V_{DCIN} - V_{BAT}}{V_{DCIN} \cdot f_{OSC}} \]

to set the bottom MOSFET on time. The result is a nearly constant switching frequency over a wide input/output voltage range. This activity is diagrammed in Figure 1.

![Figure 1](image-url)
**OPERATION**

The peak inductor current, at which I\text{CMP} resets the SR latch, is controlled by the voltage on ITH. ITH is in turn controlled by several loops, depending upon the situation at hand. The average current control loop converts the voltage between CSP and BAT to a representative current. Error amp CA2 compares this current against the desired current programmed by RPROG at the PROG pin and adjusts ITH until:

\[
\frac{V_{\text{REF}}}{R_{\text{PROG}}} = \frac{V_{\text{CSP}} - V_{\text{BAT}} + 11.67 \mu A \cdot 3.01 k\Omega}{3.01 k\Omega}
\]

therefore,

\[
I_{\text{CHARGE(MAX)}} = \left( \frac{V_{\text{REF}}}{R_{\text{PROG}}} - 11.67 \mu A \right) \cdot \frac{3.01 k\Omega}{R_{\text{SENSE}}}
\]

The voltage at BAT is divided down by an internal resistor divider and is used by error amp EA to decrease ITH if the divider voltage is above the 1.19V reference. When the charging current begins to decrease, the voltage at PROG will decrease in direct proportion. The voltage at PROG is then given by:

\[
V_{\text{PROG}} = (I_{\text{CHARGE}} \cdot R_{\text{SENSE}} + 11.67 \mu A \cdot 3.01 k\Omega) \cdot \frac{R_{\text{PROG}}}{3.01 k\Omega}
\]

V\text{PROG} is plotted in Figure 2.

The amplifier CL1 monitors and limits the input current, normally from the AC adapter to a preset level (100mV/ R\text{CL}). At input current limit, CL1 will decrease the ITH voltage, thereby reducing charging current. The I\text{CL} indicator output will go low when this condition is detected and the FLAG indicator will be inhibited if it is not already LOW.

If the charging current decreases below 10% to 15% of programmed current while engaged in input current limiting, BGATE will be forced low to prevent the charger from discharging the battery. Audible noise can occur in this mode of operation.

An overvoltage comparator guards against voltage transient overshoots (>7% of programmed value). In this case, both MOSFETs are turned off until the overvoltage condition is cleared. This feature is useful for batteries which “load dump” themselves by opening their protection switch to perform functions such as calibration or pulse mode charging.

**PWM Watchdog Timer**

There is a watchdog timer that observes the activity on the BGATE and TGATE pins. If TGATE stops switching for more than 40µs, the watchdog activates and turns off the top MOSFET for about 400ns. The watchdog engages to prevent very low frequency operation in dropout—a potential source of audible noise when using ceramic input and output capacitors.

**Charger Start-Up**

When the charger is enabled, it will not begin switching until the ITH voltage exceeds a threshold that assures initial current will be positive. This threshold is 5% to 15% of the maximum programmed current. After the charger begins switching, the various loops will control the current at a level that is higher or lower than the initial current. The duration of this transient condition depends upon the loop compensation, but is typically less than 100µs.

**Thermistor Detection**

The thermistor detection circuit is shown in Figure 3. It requires an external resistor and capacitor in order to function properly.

The thermistor detector performs a sample-and-hold function. An internal clock, whose frequency is determined...
by the timing resistor connected to $R_T$, keeps switch S1 closed to sample the thermistor:

$$t_{\text{SAMPLE}} = 127.5 \cdot 20 \cdot R_{RT} \cdot 17.5\text{pF} = 13.8\text{ms},$$

for $R_{RT} = 309k$

The external RC network is driven to approximately 4.5V and settles to a final value across the thermistor of:

$$V_{RTH(\text{FINAL})} = \frac{4.5V \cdot R_{TH}}{R_{TH} + R_9}$$

This voltage is stored by $C7$. Then the switch is opened for a short period of time to read the voltage across the thermistor.

$$t_{\text{HOLD}} = 10 \cdot R_{RT} \cdot 17.5\text{pF} = 54\mu s,$$

for $R_{RT} = 309k$

When the $t_{\text{HOLD}}$ interval ends the result of the thermistor testing is stored in the D flip-flop (DFF). If the voltage at NTC is within the limits provided by the resistor divider feeding the comparators, then the NOR gate output will be low and the DFF will set $T_{BAD}$ to zero and charging will continue. If the voltage at NTC is outside of the resistor divider limits, then the DFF will set $T_{BAD}$ to one, the charger will be shut down, FAULT pin is set low and the timer will be suspended until $T_{BAD}$ returns to zero (see Figure 4).

![Figure 3.](image1)

![Figure 4.](image2)
APPLICATIONS INFORMATION

Battery Detection

It is generally not good practice to connect a battery while the charger is running. The timer is in an unknown state and the charger could provide a large surge current into the battery for a brief time. The Figure 5 circuit keeps the charger shut down and the timer reset while a battery is not connected.

Charger Current Programming

The basic formula for charging current is:

\[ I_{\text{CHARGE(MAX)}} = \frac{V_{\text{REF}} \cdot 3.01\, \text{k} \Omega / R_{\text{PROG}} - 0.035V}{R_{\text{SENSE}}} \]

\[ V_{\text{REF}} = 1.19V \]

This leaves two degrees of freedom: \( R_{\text{SENSE}} \) and \( R_{\text{PROG}} \). The 3.0k input resistors must not be altered since internal currents and voltages are trimmed for this value. Pick \( R_{\text{SENSE}} \) by setting the average voltage between \( C_{\text{SP}} \) and \( \text{BAT} \) to be close to 100mV during maximum charger current. Then \( R_{\text{PROG}} \) can be determined by solving the above equation for \( R_{\text{PROG}} \).

\[ R_{\text{PROG}} = \frac{V_{\text{REF}} \cdot 3.01\, \text{k} \Omega}{R_{\text{SENSE}} \cdot I_{\text{CHARGE(MAX)}} + 0.035V} \]

<table>
<thead>
<tr>
<th>( I_{\text{MAX}} ) (A)</th>
<th>( R_{\text{SENSE}} ) (Ω) 1%</th>
<th>( R_{\text{SENSE}} ) (W)</th>
<th>( R_{\text{PROG}} ) (kΩ) 1%</th>
</tr>
</thead>
<tbody>
<tr>
<td>1.0</td>
<td>0.100</td>
<td>0.25</td>
<td>26.7</td>
</tr>
<tr>
<td>2.0</td>
<td>0.050</td>
<td>0.25</td>
<td>26.7</td>
</tr>
<tr>
<td>3.0</td>
<td>0.033</td>
<td>0.5</td>
<td>26.7</td>
</tr>
<tr>
<td>4.0</td>
<td>0.025</td>
<td>0.5</td>
<td>26.7</td>
</tr>
</tbody>
</table>

Maintaining C/10 Accuracy

The C/10 comparator threshold that drives the \( \text{FLAG} \) pin has a fixed threshold of approximately \( V_{\text{PROG}} = 400\text{mV} \). This threshold works well when \( R_{\text{PROG}} \) is 26.7k, but will not yield a 10% charging current indication if \( R_{\text{PROG}} \) is a different value. There are situations where a standard value of \( R_{\text{SENSE}} \) will not allow the desired value of charging current when using the preferred \( R_{\text{PROG}} \) value. In these cases, where the full-scale voltage across \( R_{\text{SENSE}} \) is within \( \pm20\text{mV} \) of the 100mV full-scale target, the input resistors connected to \( C_{\text{SP}} \) and \( \text{BAT} \) can be adjusted to provide the desired maximum programming current as well as the correct \( \text{FLAG} \) trip point.

For example, the desired max charging current is 2.5A but the best \( R_{\text{SENSE}} \) value is 0.033Ω. In this case, the voltage across \( R_{\text{SENSE}} \) at maximum charging current is only 82.5mV, normally \( R_{\text{PROG}} \) would be 30.1k but the nominal \( \text{FLAG} \) trip point is only 5% of maximum charging current. If the input resistors are reduced by the same amount as
the full-scale voltage is reduced then, R4 = R5 = 2.49k and RPROG = 26.7k, the maximum charging current is still 2.5A but the FLAG trip point is maintained at 10% of full scale.

There are other effects to consider. The voltage across the current comparator is scaled to obtain the same values as the 100mV sense voltage target, but the input referred sense voltage is reduced, causing some careful consideration of the ripple current. Input referred maximum comparator threshold is 117mV, which is the same ratio of 1.4x the DC target. Input referred IREV threshold is scaled back to –24mV. The current at which the switcher starts will be reduced as well so there is some risk of boost activity. These concerns can be addressed by using a slightly larger inductor to compensate for the reduction of tolerance to ripple current.

**Charger Voltage Programming**

Pins CHEM and C3C4 are used to program the charger final output voltage. The CHEM pin programs Li-Ion battery chemistry for 4.1V/cell (low) or 4.2V/cell (high). The C3C4 pin selects either 3 series cells (low) or 4 series cells (high). It is recommended that these pins be shorted to ground (logic low) or left open (logic high) to effect the desired logic level. Use open-collector or open-drain outputs when interfacing to the CHEM and 3C4C pins from a logic control circuit.

<table>
<thead>
<tr>
<th>VFINAL (V)</th>
<th>3C4C</th>
<th>CHEM</th>
</tr>
</thead>
<tbody>
<tr>
<td>12.3</td>
<td>LOW</td>
<td>LOW</td>
</tr>
<tr>
<td>12.6</td>
<td>LOW</td>
<td>HIGH</td>
</tr>
<tr>
<td>16.4</td>
<td>HIGH</td>
<td>LOW</td>
</tr>
<tr>
<td>16.8</td>
<td>HIGH</td>
<td>HIGH</td>
</tr>
</tbody>
</table>

**Setting the Timer Resistor**

The charger termination timer is designed for a range of 1 hour to 3 hour with a ±15% uncertainty. The timer is programmed by the resistor RRT using the following equation:

\[ t_{\text{TIMER}} = 10 \times 2^{27} \times RRT \times 17.5\text{pF (seconds)} \]

**Soft-Start**

The LTC4007 is soft started by the 0.12µF capacitor on the ITH pin. On start-up, ITH pin voltage will rise quickly to 0.5V, then ramp up at a rate set by the internal 40µA pull-up current and the external capacitor. Battery charging current starts ramping up when ITH voltage reaches 0.8V and full current is achieved with ITH at 2V. With a 0.12µF capacitor, time to reach full charge current is about 2ms and it is assumed that input voltage to the charger will reach full value in less than 2ms. The capacitor can be increased up to 1µF if longer input start-up times are needed.

**Input and Output Capacitors**

The input capacitor (C2) is assumed to absorb all input switching ripple current in the converter, so it must have adequate ripple current rating. Worst-case RMS ripple current will be equal to one half of output charging current. Actual capacitance value is not critical. Solid tantalum low ESR capacitors have high ripple current rating in a relatively small surface mount package, but caution

![Figure 7. tTIMER vs RRT](image)
APPLICATIONS INFORMATION

must be used when tantalum capacitors are used for input or output bypass. High input surge currents can be created when the adapter is hot-plugged to the charger or when a battery is connected to the charger. Solid tantalum capacitors have a known failure mechanism when subjected to very high turn-on surge currents. Kemet T495 series of “Surge Robust” low ESR tantalums are rated for high surge conditions such as battery to ground.

The relatively high ESR of an aluminum electrolytic for C1, located at the AC adapter input terminal, is helpful in reducing ringing during the hot-plug event. Refer to AN88 for more information.

Highest possible voltage rating on the capacitor will minimize problems. Consult with the manufacturer before use. Alternatives include high capacity ceramic (at least 20µF) from Tokin, United Chemi-Con/Marcon, et al. Other alternative capacitors include OS-CON capacitors from Sanyo.

The output capacitor (C3) is also assumed to absorb output switching current ripple. The general formula for capacitor current is:

\[ I_{RMS} = \frac{0.29(V_{BAT})(1 - \frac{V_{BAT}}{V_{DCIN}})}{(L)(f)} \]

For example:

\[ V_{DCIN} = 19V, \; V_{BAT} = 12.6V, \; L = 10\mu H, \; \text{and} \; f = 300kHz, \; I_{RMS} = 0.41A. \]

EMI considerations usually make it desirable to minimize ripple current in the battery leads, and beads or inductors may be added to increase battery impedance at the 300kHz switching frequency. Switching ripple current splits between the battery and the output capacitor depending on the ESR of the output capacitor and the battery impedance. If the ESR of C3 is 0.2Ω and the battery impedance is raised to 4Ω with a bead or inductor, only 5% of the current ripple will flow in the battery.

Inductor Selection

Higher operating frequencies allow the use of smaller inductor and capacitor values. A higher frequency generally results in lower efficiency because of MOSFET gate charge losses. In addition, the effect of inductor value on ripple current and low current operation must also be considered. The inductor ripple current \( \Delta_I_L \) decreases with higher frequency and increases with higher \( V_{IN} \).

\[ \Delta_I_L = \frac{1}{(f)(L)} V_{OUT} \left( 1 - \frac{V_{OUT}}{V_{IN}} \right) \]

Accepting larger values of \( \Delta_I_L \) allows the use of low inductances, but results in higher output voltage ripple and greater core losses. A reasonable starting point for setting ripple current is \( \Delta_I_L = 0.4(I_{MAX}) \). In no case should \( \Delta_I_L \) exceed 0.6\( (I_{MAX}) \) due to limits imposed by \( I_{REV} \) and CA1. Remember the maximum \( \Delta_I_L \) occurs at the maximum input voltage. In practice 10µH is the lowest value recommended for use.

Lower charger currents generally call for larger inductor values. Use Table 4 as a guide for selecting the correct inductor value for your application.

Table 4.

<table>
<thead>
<tr>
<th>MAX AVERAGE CURRENT (A)</th>
<th>INPUT VOLTAGE (V)</th>
<th>MINIMUM INDUCTOR VALUE (µH)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>≤20</td>
<td>40 ±20%</td>
</tr>
<tr>
<td>1</td>
<td>&gt;20</td>
<td>56 ±20%</td>
</tr>
<tr>
<td>2</td>
<td>≤20</td>
<td>20 ±20%</td>
</tr>
<tr>
<td>2</td>
<td>&gt;20</td>
<td>30 ±20%</td>
</tr>
<tr>
<td>3</td>
<td>≤20</td>
<td>15 ±20%</td>
</tr>
<tr>
<td>3</td>
<td>&gt;20</td>
<td>20 ±20%</td>
</tr>
<tr>
<td>4</td>
<td>≤20</td>
<td>10 ±20%</td>
</tr>
<tr>
<td>4</td>
<td>&gt;20</td>
<td>15 ±20%</td>
</tr>
</tbody>
</table>
APPLICATIONS INFORMATION

Charger Switching Power MOSFET and Diode Selection

Two external power MOSFETs must be selected for use with the charger: a P-channel MOSFET for the top (main) switch and an N-channel MOSFET for the bottom (synchronous) switch.

The peak-to-peak gate drive levels are set internally. This voltage is typically 6V. Consequently, logic-level threshold MOSFETs must be used. Pay close attention to the BV_{DSS} specification for the MOSFETs as well; many of the logic level MOSFETs are limited to 30V or less.

Selection criteria for the power MOSFETs include the “ON” resistance $R_{DS(ON)}$, total gate capacitance $Q_G$, reverse transfer capacitance $C_{RSS}$, input voltage and maximum output current. The charger is operating in continuous mode at moderate to high currents so the duty cycles for the top and bottom MOSFETs are given by:

- **Main Switch Duty Cycle** = $V_{OUT}/V_{IN}$
- **Synchronous Switch Duty Cycle** = $(V_{IN} - V_{OUT})/V_{IN}$

The MOSFET power dissipations at maximum output current are given by:

$P_{MAIN} = V_{OUT}/V_{IN}(I_{MAX})^2(1 + \delta\Delta T)R_{DS(ON)} + k(V_{IN})^2(I_{MAX})(C_{RSS})(f_{OSC})$

$P_{SYNC} = (V_{IN} - V_{OUT})/V_{IN}(I_{MAX})^2(1 + \delta\Delta T)R_{DS(ON)}$

Where $\delta\Delta T$ is the temperature dependency of $R_{DS(ON)}$ and $k$ is a constant inversely related to the gate drive current. Both MOSFETs have $I^2R$ losses while the $P_{MAIN}$ equation includes an additional term for transition losses, which are highest at high input voltages. For $V_{IN} < 20V$ the high current efficiency generally improves with larger MOSFETs, while for $V_{IN} > 20V$ the transition losses rapidly increase to the point that the use of a higher $R_{DS(ON)}$ device with lower $C_{RSS}$ actually provides higher efficiency. The synchronous MOSFET losses are greatest at high input voltage or during a short circuit when the duty cycle in this switch is nearly 100%. The term $(1 + \delta\Delta T)$ is generally given for a MOSFET in the form of a normalized $R_{DS(ON)}$ vs temperature curve, but $\delta = 0.005/°C$ can be used as an approximation for low voltage MOSFETs. $C_{RSS} = Q_{GD}/\Delta V_{DS}$ is usually specified in the MOSFET characteristics. The constant $k = 2$ can be used to estimate the contributions of the two terms in the main switch dissipation equation.

If the charger is to operate in low dropout mode or with a high duty cycle greater than 85%, then the topside P-channel efficiency generally improves with a larger MOSFET. Using asymmetrical MOSFETs may achieve cost savings or efficiency gains.

The Schottky diode D1, shown in the Typical Application on the back page, conducts during the dead-time between the conduction of the two power MOSFETs. This prevents the body diode of the bottom MOSFET from turning on and storing charge during the dead-time, which could cost as much as 1% in efficiency. A 1A Schottky is generally a good size for 4A regulators due to the relatively small average current. Larger diodes can result in additional transition losses due to their larger junction capacitance. The diode may be omitted if the efficiency loss can be tolerated.

Calculating IC Power Dissipation

The power dissipation of the LTC4007 is dependent upon the gate charge of the top and bottom MOSFETs (QG1 & QG2 respectively). The gate charge is determined from the manufacturer’s data sheet and is dependent upon both the gate voltage swing and the drain voltage swing of the MOSFET. Use 6V for the gate voltage swing and $V_{DCIN}$ for the drain voltage swing.

$PD = V_{DCIN} \cdot (f_{OSC} \cdot (QG1 + QG2) + I_Q)$

Example:

$V_{DCIN} = 19V, f_{OSC} = 345kHz, QG1 = QG2 = 15nC, I_Q = 5mA$

$PD = 292mW$
APPLICATIONS INFORMATION

Adapter Limiting

An important feature of the LTC4007 is the ability to automatically adjust charging current to a level which avoids overloading the wall adapter. This allows the product to operate at the same time that batteries are being charged without complex load management algorithms. Additionally, batteries will automatically be charged at the maximum possible rate of which the adapter is capable.

This feature is created by sensing total adapter output current and adjusting charging current downward if a preset adapter current limit is exceeded. True analog control is used, with closed-loop feedback ensuring that adapter load current remains within limits. Amplifier CL1 in Figure 8 senses the voltage across R\textsubscript{CL}, connected between the CLP and CLN pins. When this voltage exceeds 100mV, the amplifier will override programmed charging current to limit adapter current to 100mV/R\textsubscript{CL}. A lowpass filter formed by 5k\Omega and 15nF is required to eliminate switching noise. If the current limit is not used, CLP and CLN should be connected together and tied to DCIN.

Note that the I\textsubscript{CL} pin will be asserted when the voltage across R\textsubscript{CL} is 93mV, before the adapter limit regulation threshold.

![Figure 8. Adapter Current Limiting](image)

Setting Input Current Limit

To set the input current limit, you need to know the minimum wall adapter current rating. Subtract 7% for the input current limit tolerance and use that current to determine the resistor value.

\[
R_{CL} = \frac{100mV}{I_{LIM}} \\
I_{LIM} = \text{Adapter Min Current} - (\text{Adapter Min Current} \cdot 7\%)
\]

Table 5. Common R\textsubscript{CL} Resistor Values

<table>
<thead>
<tr>
<th>ADAPTER RATING (A)</th>
<th>R\textsubscript{CL} VALUE* (Ω)</th>
<th>R\textsubscript{CL} POWER DISSIPATION (W)</th>
<th>R\textsubscript{CL} POWER RATING (W)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1.5</td>
<td>0.06</td>
<td>0.135</td>
<td>0.25</td>
</tr>
<tr>
<td>1.8</td>
<td>0.05</td>
<td>0.162</td>
<td>0.25</td>
</tr>
<tr>
<td>2</td>
<td>0.045</td>
<td>0.18</td>
<td>0.25</td>
</tr>
<tr>
<td>2.3</td>
<td>0.039</td>
<td>0.206</td>
<td>0.25</td>
</tr>
<tr>
<td>2.5</td>
<td>0.036</td>
<td>0.225</td>
<td>0.5</td>
</tr>
<tr>
<td>2.7</td>
<td>0.033</td>
<td>0.241</td>
<td>0.5</td>
</tr>
<tr>
<td>3</td>
<td>0.03</td>
<td>0.27</td>
<td>0.5</td>
</tr>
</tbody>
</table>

* Values shown above are rounded to nearest standard value.

As is often the case, the wall adapter will usually have at least a +10% current limit margin and many times one can simply set the adapter current limit value to the actual adapter rating (see Table 5).

Designing the Thermistor Network

There are several networks that will yield the desired function of voltage vs temperature needed for proper operation of the thermistor. The simplest of these is the voltage divider shown in Figure 9. Unfortunately, since the HIGH/LOW comparator thresholds are fixed internally, there is only one thermistor type that can be used in this network; the thermistor must have a HIGH/LOW resistance ratio of 1:7. If this happy circumstance is true for you, then simply set R9 = R\textsubscript{TH(LOW)}.

![Figure 9. Voltage Divider Thermistor Network](image)
If you are using a thermistor that doesn’t have a 1:7 HIGH/LOW ratio, or you wish to set the HIGH/LOW limits to different temperatures, then the more generic network in Figure 10 should work.

Once the thermistor, \( R_{TH} \), has been selected and the thermistor value is known at the temperature limits, then resistors \( R_9 \) and \( R_{9A} \) are given by:

For NTC thermistors:

\[
R_9 = 6 \cdot R_{TH(LOW)} \cdot \frac{R_{TH(HIGH)}}{R_{TH(LOW)} - \frac{7 \cdot R_{TH(HIGH)}}{R_{TH(HIGH)}}}
\]

\[
R_{9A} = 6 R_{TH(LOW)} \cdot \frac{R_{TH(HIGH)}}{R_{TH(LOW)} - 7 \cdot R_{TH(HIGH)}}
\]

Where \( R_{TH(LOW)} > 7 \cdot R_{TH(HIGH)} \)

For PTC thermistors:

\[
R_9 = 6 \cdot R_{TH(LOW)} \cdot \frac{R_{TH(HIGH)}}{R_{TH(HIGH)} - \frac{R_{TH(LOW)}}{R_{TH(LOW)}}}
\]

\[
R_{9A} = 6 R_{TH(LOW)} \cdot \frac{R_{TH(HIGH)}}{R_{TH(HIGH)} - 7 \cdot R_{TH(LOW)}}
\]

Where \( R_{TH(HIGH)} > 7 \cdot R_{TH(LOW)} \)

Example #1: 10kΩ NTC with custom limits

\[
T_{LOW} = 0°C, \quad T_{HIGH} = 50°C
\]

\[
R_{TH} = 10k \text{ at } 25°C,
\]

\[
R_{TH(LOW)} = 32.582k \text{ at } 0°C
\]

\[
R_{TH(HIGH)} = 3.635k \text{ at } 50°C
\]

\[
R_9 = 24.55k \rightarrow 24.3k \text{ (nearest 1% value)}
\]

\[
R_{9A} = 99.6k \rightarrow 100k \text{ (nearest 1% value)}
\]

Example #2: 100kΩ NTC

\[
T_{LOW} = 5°C, \quad T_{HIGH} = 50°C
\]

\[
R_{TH} = 100k \text{ at } 25°C,
\]

\[
R_{TH(LOW)} = 272.05k \text{ at } 5°C
\]

\[
R_{TH(HIGH)} = 33.195k \text{ at } 50°C
\]

\[
R_9 = 226.9k \rightarrow 226k \text{ (nearest 1% value)}
\]

\[
R_{9A} = 1.365M \rightarrow 1.37M \text{ (nearest 1% value)}
\]

Example #3: 22kΩ PTC

\[
T_{LOW} = 0°C, \quad T_{HIGH} = 50°C
\]

\[
R_{TH} = 22k \text{ at } 25°C,
\]

\[
R_{TH(LOW)} = 6.53k \text{ at } 0°C
\]

\[
R_{TH(HIGH)} = 61.4k \text{ at } 50°C
\]

\[
R_9 = 43.9k \rightarrow 44.2k \text{ (nearest 1% value)}
\]

\[
R_{9A} = 154k
\]

**Sizing the Thermistor Hold Capacitor**

During the hold interval, \( C_7 \) must hold the voltage across the thermistor relatively constant to avoid false readings. A reasonable amount of ripple on NTC during the hold interval is about 10mV to 15mV. Therefore, the value of \( C_7 \) is given by:

\[
C_7 = \frac{t_{HOLD}}{(R_9/7 \cdot \ln(1 - 8 \cdot 15mV/4.5V))}
\]

Example:

\[
R_9 = 24.3k
\]

\[
R_{RT} = 309k \text{ (~2 hour timer)}
\]

\[
C_7 = 0.57\mu F \rightarrow 0.56\mu F \text{ (nearest value)}
\]
Disabling the Thermistor Function
If the thermistor is not needed, connecting a resistor between DCIN and NTC will disable it. The resistor should be sized to provide at least 10µA with the minimum voltage applied to DCIN and 10V at NTC. Do not exceed 30µA. Generally, a 301k resistor will work for DCIN less than 15V. A 499k resistor is recommended for DCIN between 15V and 24V.

Conditioning Depleted Batteries
Severely depleted batteries, with less than 2.5V/cell, should be conditioned with a trickle charge to prevent possible damage. This trickle charge is typically 10% of the 1C rate of the battery. The LTC4007 can automatically trickle charge depleted batteries using the circuit in Figure 11. If the battery voltage is less than 2.5V/cell (2.44V/cell if CHEM is low) then the LOBAT indicator will be low and Q4 is off. This programs the charging current with \( R_{\text{PROG}} = R_6 + R_{14} \). Charging current is approximately 300mA. When the cell voltage becomes greater than 2.5V the LOBAT indicator goes high, Q4 shorts out R13, then \( R_{\text{PROG}} = R_6 \). Charging current is then equal to 3A.

PCB Layout Considerations
For maximum efficiency, the switch node rise and fall times should be minimized. To prevent magnetic and electrical field radiation and high frequency resonant problems, proper layout of the components connected to the IC is essential (see Figure 12). Here is a PCB layout priority list for proper layout. Layout the PCB using this specific order.

1. Input capacitors need to be placed as close as possible to switching FET’s supply and ground connections. Shortest copper trace connections possible. These parts must be on the same layer of copper. Vias must not be used to make this connection.
2. The control IC needs to be close to the switching FET’s gate terminals. Keep the gate drive signals short for a clean FET drive. This includes IC supply pins that connect to the switching FET source pins. The IC can be placed on the opposite side of the PCB relative to above.
3. Place inductor input as close as possible to switching FET’s output connection. Minimize the surface area of this trace. Make the trace width the minimum amount needed to support current—no copper fills or pours. Avoid running the connection using multiple layers in parallel. Minimize capacitance from this node to any other trace or plane.
4. Place the output current sense resistor right next to the inductor output but oriented such that the IC’s current sense feedback traces going to resistor are not long. The feedback traces need to be routed together as a single pair on the same layer at any given time with smallest trace spacing possible. Locate any filter component on these traces next to the IC and not at the sense resistor location.
5. Place output capacitors next to the sense resistor output and ground.
6. Output capacitor ground connections need to feed into same copper that connects to the input capacitor ground before tying back into system ground.
APPLICATIONS INFORMATION

General Rules

7. Connection of switching ground to system ground or internal ground plane should be single point. If the system has an internal system ground plane, a good way to do this is to cluster vias into a single star point to make the connection.

8. Route analog ground as a trace tied back to IC ground (analog ground pin if present) before connecting to any other ground. Avoid using the system ground plane. CAD trick: make analog ground a separate ground net and use a 0Ω resistor to tie analog ground to system ground.

9. A good rule of thumb for via count for a given high current path is to use 0.5A per via. Be consistent.

10. If possible, place all the parts listed above on the same PCB layer.

11. Copper fills or pours are good for all power connections except as noted above in Rule 3. You can also use copper planes on multiple layers in parallel too—this helps with thermal management and lower trace inductance improving EMI performance further.

12. For best current programming accuracy provide a Kelvin connection from RSENSE to CSP and BAT. See Figure 12 as an example.

It is important to keep the parasitic capacitance on the RT, CSP and BAT pins to a minimum. The traces connecting these pins to their respective resistors should be as short as possible.
Figure 11. Circuit Application (16.8V/3A) to Automatically Trickle Charge Depleted Batteries
**APPLICATIONS INFORMATION**

![High Speed Switching Path](image1)

**Figure 12. High Speed Switching Path**

![Kelvin Sensing of Charging Current](image2)

**Figure 13. Kelvin Sensing of Charging Current**

**PACKAGE DESCRIPTION**

**GN Package**

24-Lead Plastic SSOP (Narrow .150 Inch)

(Reference LTC DWG # 05-08-1641)

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**RECOMMENDED SOLDER PAD LAYOUT**

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**NOTE:**

1. CONTROLLING DIMENSION: INCHES
2. DIMENSIONS ARE IN INCHES (MILLIMETERS)
3. DRAWING NOT TO SCALE

*DIMENSION DOES NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.006” (0.152mm) PER SIDE

**DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010” (0.254mm) PER SIDE
# Revision History

Revision history begins at Rev B

<table>
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<th>REV</th>
<th>DATE</th>
<th>DESCRIPTION</th>
<th>PAGE NUMBER</th>
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<tr>
<td>B</td>
<td>7/10</td>
<td>Changed ±5% to ±4% in Description text</td>
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<tr>
<td></td>
<td></td>
<td>Updated Figure 6</td>
<td>13</td>
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<tr>
<td>C</td>
<td>8/10</td>
<td>“Charge Termination” text added</td>
<td>1, 4, 6, 9, 10, 17</td>
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<tr>
<td>D</td>
<td>4/18</td>
<td>Lowered $\theta_{JA}$ value</td>
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### TYPICAL APPLICATION

**12.6V/4A Li-Ion Battery Charger**

![Diagram of 12.6V/4A Li-Ion Battery Charger](image)

### RELATED PARTS

<table>
<thead>
<tr>
<th>PART NUMBER</th>
<th>DESCRIPTION</th>
<th>COMMENTS</th>
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<tbody>
<tr>
<td>LT®1511</td>
<td>Constant-Current/Constant-Voltage 3A Battery Charger with Input Current Limiting</td>
<td>High Efficiency Current Mode PWM with 4A Internal Switch</td>
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<tr>
<td>LT1513</td>
<td>SEPIC Constant- or Programmable-Current/ Constant-Voltage Battery Charger</td>
<td>Charger Input Voltage May Be Higher, Equal to or Lower Than Battery Voltage; Charges Any Number of Cells Up to 20V, 500kHz Switching Frequency</td>
</tr>
<tr>
<td>LT1571</td>
<td>1.5A Switching Charger</td>
<td>1- or 2-Cell Li-Ion, 500kHz or 200kHz Switching Frequency, Termination Flag</td>
</tr>
<tr>
<td>LTC1628-PG</td>
<td>2-Phase, Dual Synchronous Step-Down Controller</td>
<td>Minimizes C_IN and C_OUT, Power Good Output, 3.5V ≤ V_IN ≤ 36V</td>
</tr>
<tr>
<td>LTC1709</td>
<td>2-Phase, Dual Synchronous Step-Down Controller with VID</td>
<td>Up to 42A Output, Minimum C_IN and C_OUT, Uses Smallest Components for Intel and AMD Processors</td>
</tr>
<tr>
<td>LTC1729</td>
<td></td>
<td></td>
</tr>
<tr>
<td>LT1769</td>
<td>2A Switching Battery Charger</td>
<td>Constant-Current/Constant-Voltage Switching Regulator, Input Current Limiting Maximizes Charge Current</td>
</tr>
<tr>
<td>LTC1778</td>
<td>Wide Operating Range, No RSENSE Synchronous Step-Down Controller</td>
<td>2% to 90% Duty Cycle at 200kHz, Stable with Ceramic C_OUT</td>
</tr>
<tr>
<td>LTC1960</td>
<td>Dual Battery Charger/Selector with SPI Interface</td>
<td>Simultaneous Charge or Discharge of Two Batteries, DAC Programmable Current and Voltage, Input Current Limiting Maximizes Charge Current</td>
</tr>
<tr>
<td>LTC3711</td>
<td>No RSENSE™ Synchronous Step-Down Controller with VID</td>
<td>3.5V ≤ V_IN ≤ 36V, 0.925V ≤ V_OUT ≤ 2V, for Transmeta, AMD and Intel Mobile Processors</td>
</tr>
<tr>
<td>LTC4006</td>
<td>Small, High Efficiency, Fixed Voltage, Lithium-Ion Battery Charger</td>
<td>Constant-Current/Constant-Voltage Switching Regulator with Terminator Timer, AC Adapter Current Limit and Thermistor Sensor in a Small 16-Pin Package</td>
</tr>
<tr>
<td>LTC4008</td>
<td>High Efficiency, Programmable Voltage/Current Battery Charger</td>
<td>Constant-Current/Constant-Voltage Switching Regulator, Resistor Voltage Current Programming, AC Adapter Current Limit and Thermistor Sensor</td>
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